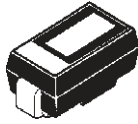
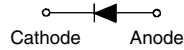


## Schottky Rectifier, 1.0 A


**SMB**

**FEATURES**

- Small foot print, surface mountable
- Low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- Lead (Pb)-free ("PbF" suffix)
- Designed and qualified for industrial level


**RoHS**  
COMPLIANT

**PRODUCT SUMMARY**

$I_{F(AV)}$	1.0 A
$V_R$	90/100 V
$I_{RM}$	1 mA at 125 °C

**DESCRIPTION**

The MBRS190TRPbF, MBRS1100TRPbF surface mount Schottky rectifier has been designed for applications requiring low forward drop and very small foot prints on PC boards. Typical applications are in disk drives, switching power supplies, converters, freewheeling diodes, battery charging, and reverse battery protection.

**MAJOR RATINGS AND CHARACTERISTICS**

SYMBOL	CHARACTERISTICS	VALUES	UNITS
$I_{F(AV)}$	Rectangular waveform	1.0	A
$V_{RRM}$		90/100	V
$I_{FSM}$	$t_p = 5 \mu s$ sine	870	A
$V_F$	1.0 Apk, $T_J = 125 \text{ }^\circ\text{C}$	0.63	V
$T_J$	Range	- 55 to 175	$^\circ\text{C}$

**VOLTAGE RATINGS**

PARAMETER	SYMBOL	MBRS190TRPbF	MBRS1100TRPbF	UNITS
Maximum DC reverse voltage	$V_R$	90	100	V
Maximum working peak reverse voltage	$V_{RWM}$			

**ABSOLUTE MAXIMUM RATINGS**

PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum average forward current	$I_{F(AV)}$	50 % duty cycle at $T_L = 147 \text{ }^\circ\text{C}$ , rectangular waveform	1.0	A
Maximum peak one cycle non-repetitive surge current	$I_{FSM}$	5 $\mu s$ sine or 3 $\mu s$ rect. pulse	870	
		10 ms sine or 6 ms rect. pulse	50	
Non-repetitive avalanche energy	$E_{AS}$	$T_J = 25 \text{ }^\circ\text{C}$ , $I_{AS} = 0.5 \text{ A}$ , $L = 8 \text{ mH}$	1.0	mJ
Repetitive avalanche current	$I_{AR}$	Current decaying linearly to zero in 1 $\mu s$ Frequency limited by $T_J$ maximum $V_A = 1.5 \times V_R$ typical	0.5	A

# MBRS190TRPbF/MBRS1100TRPbF



Vishay High Power Products Schottky Rectifier, 1.0 A

ELECTRICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum forward voltage drop See fig. 1	$V_{FM}^{(1)}$	1 A	$T_J = 25\text{ }^\circ\text{C}$	0.78	V
			$T_J = 125\text{ }^\circ\text{C}$	0.62	
Maximum reverse leakage current See fig. 2	$I_{RM}^{(1)}$	$T_J = 25\text{ }^\circ\text{C}$	$V_R = \text{Rated } V_R$	0.5	mA
		$T_J = 125\text{ }^\circ\text{C}$		1.0	
Typical junction capacitance	$C_T$	$V_R = 5 V_{DC}$ (test signal range 100 kHz to 1 MHz) 25 °C		42	pF
Typical series inductance	$L_S$	Measured lead to lead 5 mm from package body		2.0	nH
Maximum voltage rate of change	$dV/dt$	Rated $V_R$		10 000	V/ $\mu$ s

## Note

(1) Pulse width < 300  $\mu$ s, duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum junction and storage temperature range	$T_J^{(1)}, T_{Stg}$			- 55 to 175	$^\circ\text{C}$
Maximum thermal resistance, junction to lead	$R_{thJL}^{(2)}$	DC operation See fig. 4		36	$^\circ\text{C}/\text{W}$
Maximum thermal resistance, junction to ambient	$R_{thJA}$	DC operation		80	
Approximate weight				0.10	g
				0.003	oz.
Marking device		Case style SMB (similar to DO-214AA)		V19/V10	

## Notes

(1)  $\frac{dP_{tot}}{dT_J} < \frac{1}{R_{thJA}}$  thermal runaway condition for a diode on its own heatsink

(2) Mounted 1" square PCB

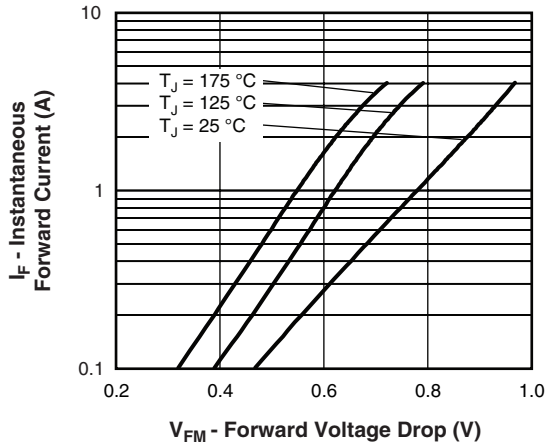


Fig. 1 - Maximum Forward Voltage Drop Characteristics

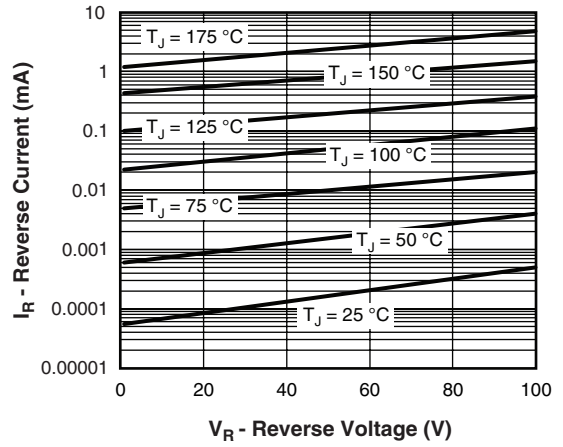


Fig. 2 - Typical Peak Reverse Current vs. Reverse Voltage

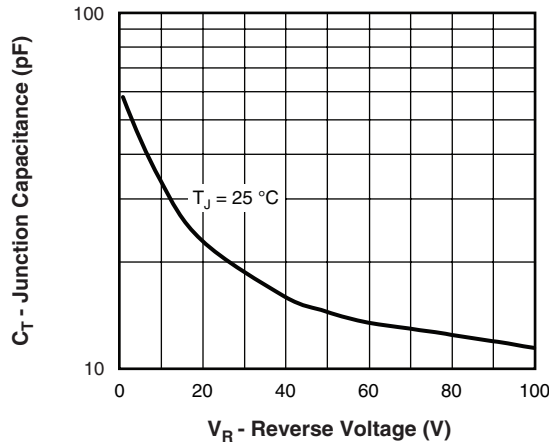


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

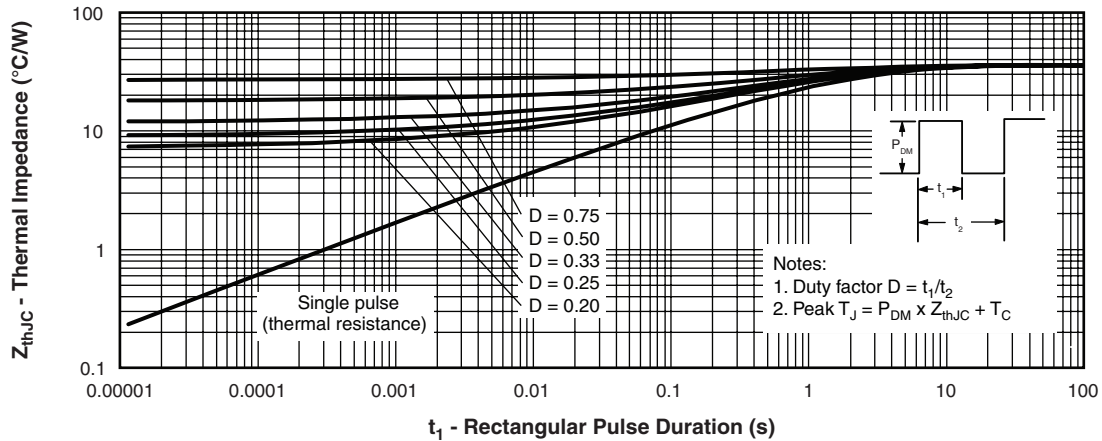


Fig. 4 - Maximum Thermal Impedance  $Z_{thJC}$  Characteristics (Per Leg)

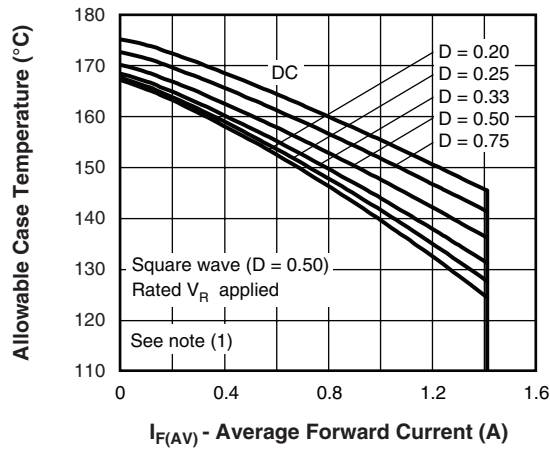


Fig. 5 - Maximum Average Forward Current vs. Allowable Lead Temperature

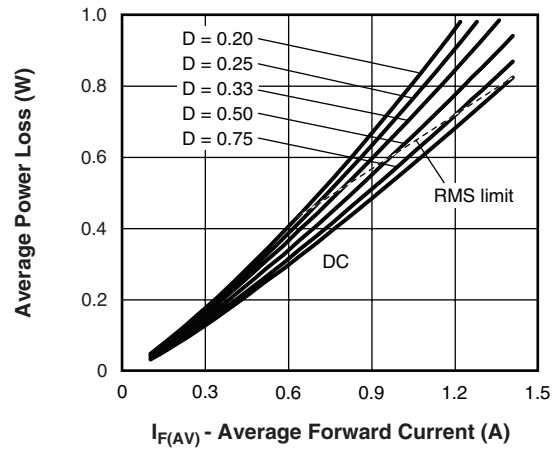


Fig. 6 - Maximum Average Forward Dissipation vs. Average Forward Current

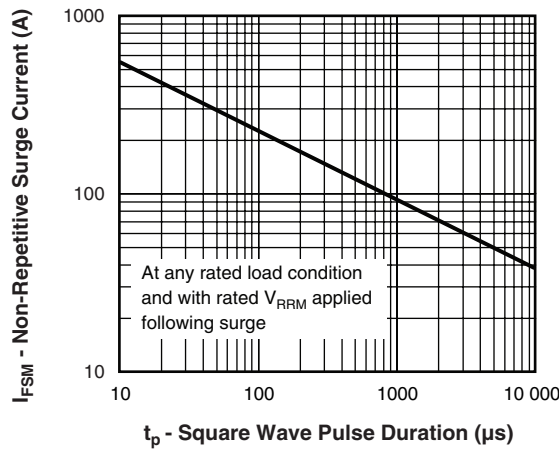


Fig. 7 - Maximum Peak Surge Forward Current vs. Pulse Duration

**Note**

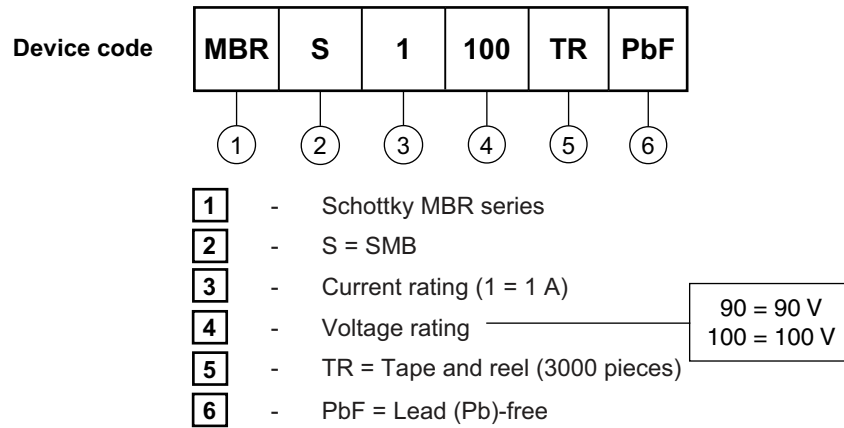
- (1) Formula used:  $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$ ;  
 $Pd$  = Forward power loss =  $I_{F(AV)} \times V_{FM}$  at  $(I_{F(AV)}/D)$  (see fig. 6);  
 $Pd_{REV}$  = Inverse power loss =  $V_{R1} \times I_R (1 - D)$ ;  $I_R$  at  $V_{R1} = 80\%$  rated  $V_R$



# MBRS190TRPbF/MBRS1100TRPbF

Schottky Rectifier, 1.0 A Vishay High Power Products

## ORDERING INFORMATION TABLE



LINKS TO RELATED DOCUMENTS	
Dimensions	<a href="http://www.vishay.com/doc?95017">http://www.vishay.com/doc?95017</a>
Part marking information	<a href="http://www.vishay.com/doc?95029">http://www.vishay.com/doc?95029</a>
Packaging information	<a href="http://www.vishay.com/doc?95034">http://www.vishay.com/doc?95034</a>



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